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November 2013

FDP039N08B N-Channel PowerTrench[®] MOSFET 80 V, 171 A, 3.9 m Ω

Features

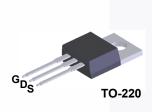
- $R_{DS(on)}$ = 3.16 m Ω (Typ.) @ V_{GS} = 10 V, I_D = 100 A
- Low FOM $R_{DS(on)} * Q_G$
- Low Reverse-Recovery Charge, Q_{rr} = 87.9 nC
- Soft Reverse-Recovery Body Diode
- Enables High Efficiency in Synchronous Rectification
- Fast Switching Speed
- 100% UIL Tested
- RoHS Compliant

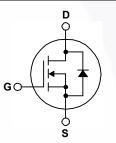
Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench[®] process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

Applications

- Synchronous Rectification for ATX / Server / Telecom PSU
- Battery Protection Circuit
- Motor Drives and Uninterruptible Power Supplies





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

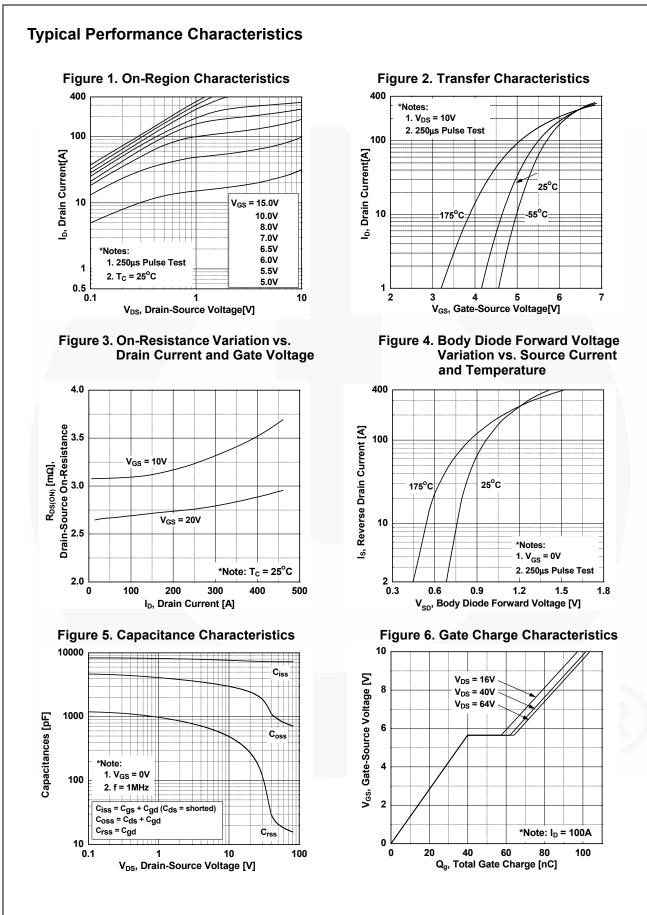
Symbol		FDP039N08B_F102	Unit		
V _{DSS}	Drain to Source Voltage	80	V		
V _{GSS}	Gate to Source Voltage		±20	V	
ID		- Continuous (T _C = 25°C, Silicon Limited)	171*		
	Drain Current	- Continuous (T _C = 100°C, Silicon Limited)	121*	A	
		- Continuous (T _C = 25°C, Package Limited)	120		
I _{DM}	Drain Current	- Pulsed (Note 1)	684	Α	
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		547	mJ	
dv/dt	Peak Diode Recovery dv/dt (Note 3)		6.0	V/ns	
P _D	Power Discipation	$(T_{\rm C} = 25^{\rm o}{\rm C})$	214	W	
	Power Dissipation	- Derate Above 25°C	1.43	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +175	°C	
TL	Maximum Lead Temperature for S	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		°C	

* Package limitation current is 120A.

Thermal Characteristics

Symbol	Parameter	FDP039N08B_F102	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	0.7	°C/W
$R_{ heta JA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	0/00

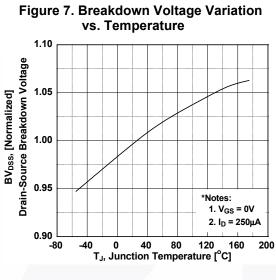
	nber	Part Number Top Mark Packag		e Packing Method Reel Size		Тар	e Width	Qua	ntity
FDP039N08	B_F102	FDP039N08B	TO-220	Tube	N/A		N/A	50 u	units
Electrical	Chara	acteristics T _c =	= 25°C unless	otherwise noted.					
Symbol	Parameter			Test Conditions		Min.	Тур.	Max.	Unit
Off Charact	eristics	5							
BV _{DSS}	Drain to	Source Breakdown \	/oltage	I _D = 250 μA, V _{GS} = 0	V	80	-	-	V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient		0	$I_D = 250 \ \mu\text{A}, \ \text{V}_{\text{GS}} = 0 \ \text{V}$ $I_D = 250 \ \mu\text{A}, \ \text{Referenced to } 25^{\circ}\text{C}$		-	0.089	-	V/ºC
				V _{DS} = 64 V, V _{GS} = 0 V		-	-	1	
DSS	Zero Ga	te Voltage Drain Curr	ent	$V_{\rm DS} = 64 \text{ V}, \text{ T}_{\rm C} = 150^{\circ}\text{C}$		-	-	500	μA
GSS	Gate to Body Leakage Current		nt	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0$		-	-	±100	nA
On Charact	eristics	5							
V _{GS(th)}	Gate Th	reshold Voltage		V _{GS} = V _{DS} , I _D = 250 μ	A	2.5	-	4.5	V
RDS(on)		ain to Source On Re	sistance	$V_{GS} = V_{DS}, I_D = 250 \mu\text{A}$ $V_{GS} = 10 \text{V}, I_D = 100 \text{A}$		-	3.16	3.9	mΩ
JFS		Transconductance		$V_{\rm DS} = 10 \text{ V}, \text{ I}_{\rm D} = 100 \text{ A}$		-	180	-	S
Dynamic Cl	haracte	ristics							-1
C _{iss}	Input Ca	pacitance		$V_{DS} = 40 \text{ V}, \text{ V}_{GS} = 0 \text{ V},$ f = 1 MHz		-	7105	9450	pF
C _{oss}	Output C	Capacitance				-	1110	1475	pF
Crss	Reverse	rse Transfer Capacitance				-	30	-	pF
C _{oss(er)}	Energy F	Energy Related Output Capacitance		V _{DS} = 40 V, V _{GS} = 0 V		-	1656	-	pF
Q _{g(tot)}	Total Gat	te Charge at 10V					102	133	nC
2 _{gs}	Gate to S	te to Source Gate Charge		$V_{DS} = 40 V, I_{D} = 100 A,$		-	39.9	-	nC
Q _{gd}	Gate to I	Drain "Miller" Charge		V _{GS} = 10 V		-	22	-	nC
∕ _{plateau}	Gate Pla	lateau Volatge (No		(Note 4)	-	5.6	-	V	
Q _{sync}	Total Gate Charge Sync.			V _{DS} = 0 V, I _D = 50 A		-	87.4	-	nC
Q _{oss}	Output Charge		_	$V_{DS} = 40 V, V_{GS} = 0 V$		-	99.2	-	nC
Switching C	Charact	eristics							
d(on)	Turn-On	Delay Time				-	36	82	ns
r	Turn-On	Rise Time		V _{DD} = 40 V, I _D = 100 A,		-	49	108	ns
d(off)	Turn-Off Delay Time		V_{GS} = 10 V, R_{G} = 4.7 Ω		-	71	152	ns	
f	Turn-Off	Fall Time		(Note 4)		-	29	68	ns
ESR	Equivale	nt Series Resistance	(G-S)	f = 1 MHz		-	2.2	-	Ω
Drain-Sour	ce Diod	e Characteristic	s						
S	Maximun	n Continuous Drain to	Source Diod	e Forward Current		-	-	171*	Α
SM	Maximum Pulsed Drain to Source Diode F		urce Diode Fo	orward Current		-	-	684	Α
/ _{SD}	Drain to Source Diode Forward Voltage		d Voltage	V _{GS} = 0 V, I _{SD} = 100 A		-	-	1.3	V
r	Reverse Recovery Time			$V_{GS} = 0 V, V_{DD} = 40 V, I_{SD} = 100 A,$		-	70.1		ns
2 ^u	Reverse Recovery Charge			$dI_F/dt = 100 \text{ A/}\mu\text{s}$		-	87.9		nC



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Typical Performance Characteristics (Continued)





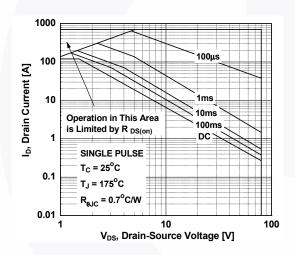
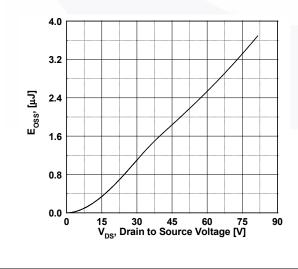
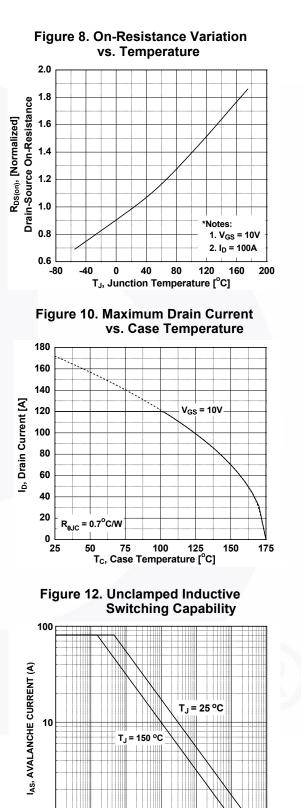


Figure 11. Eoss vs. Drain to Source Voltage





0.001

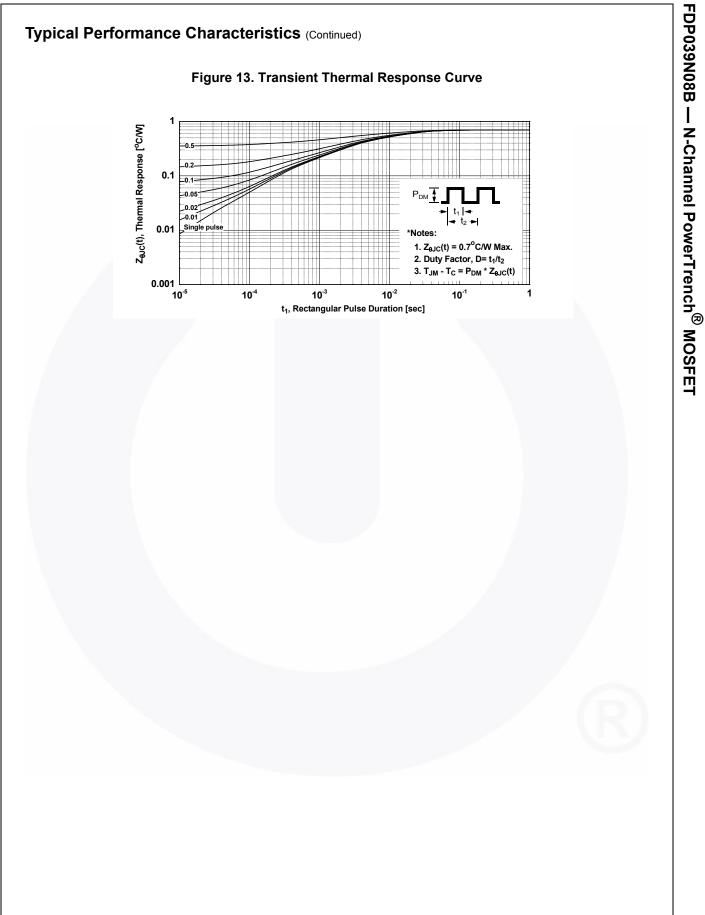
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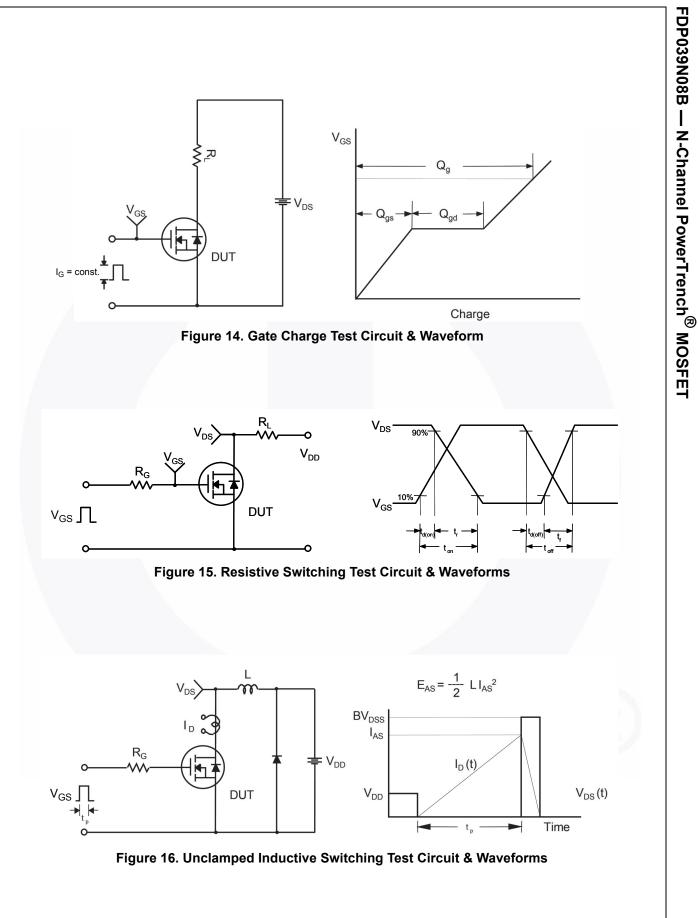
0.1

1 t_{AV}, TIME IN AVALANCHE (ms) 1000

100

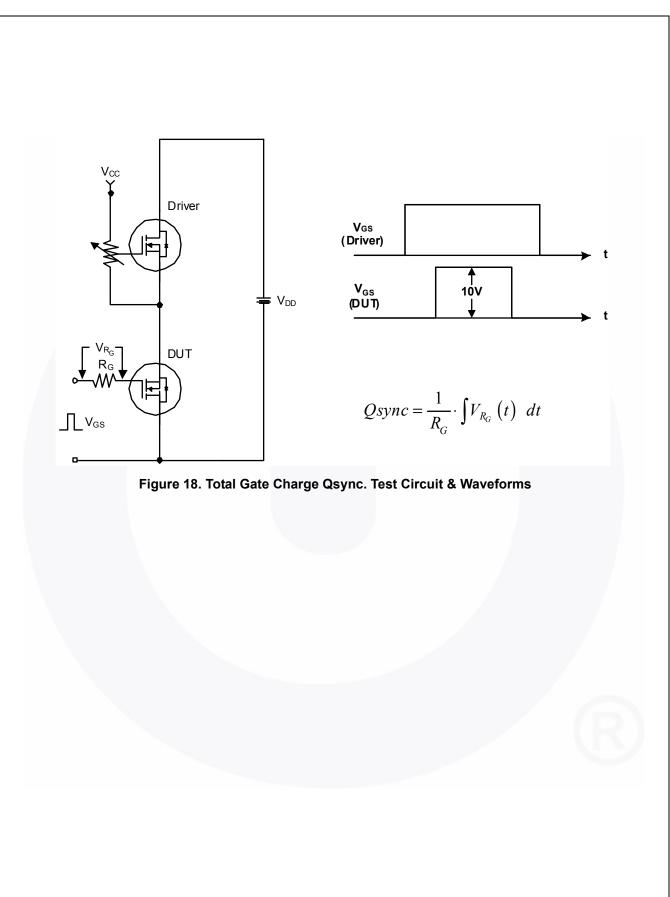
10

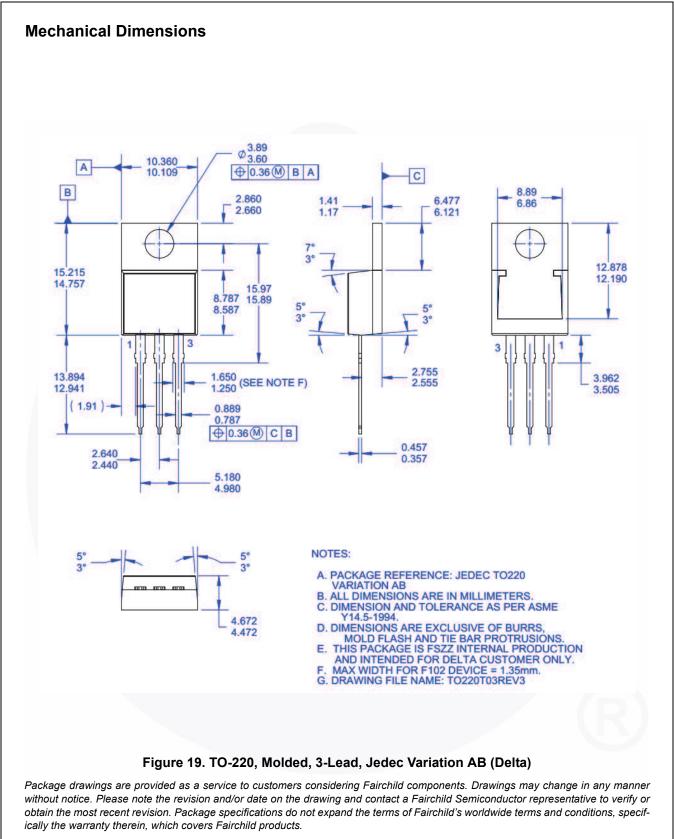




DUT + v_{DS} a ۱_{SD} م L Driver R_G€ Same Type as DUT L F ∨_{DD} $\prod V_{GS}$ • dv/dt controlled by R_{G} • I_{SD} controlled by pulse period Î Gate Pulse Width V_{GS} D = Gate Pulse Period 10V (Driver) I_{FM}, Body Diode Forward Current I _{SD} di/dt (DUT) I_{RM} Body Diode Reverse Current V_{DS} (DUT) Body Diode Recovery dv/dt V_{SD} V_{DD} Body Diode Forward Voltage Drop Figure 17. Peak Diode Recovery dv/dt Test Circuit & Waveforms

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